

BD235

Rev.E Mar.-2016

Silicon NPN transistor in a TO-126F Plastic Package.

Complementary pair with BD236.

BD235

Rev.E Mar.-2016

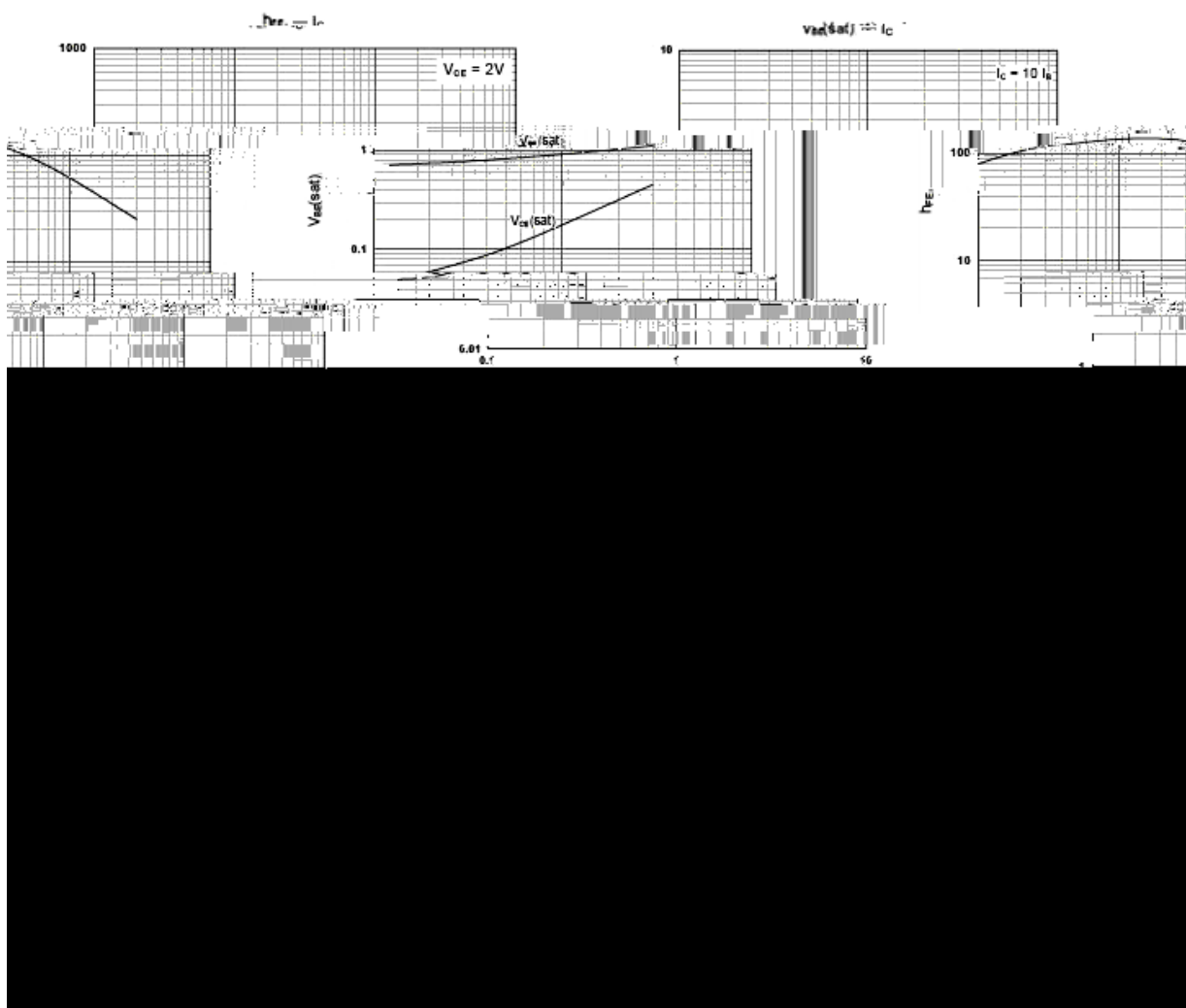


蓝箭电子
BLUE ROCKET ELECTRONICS

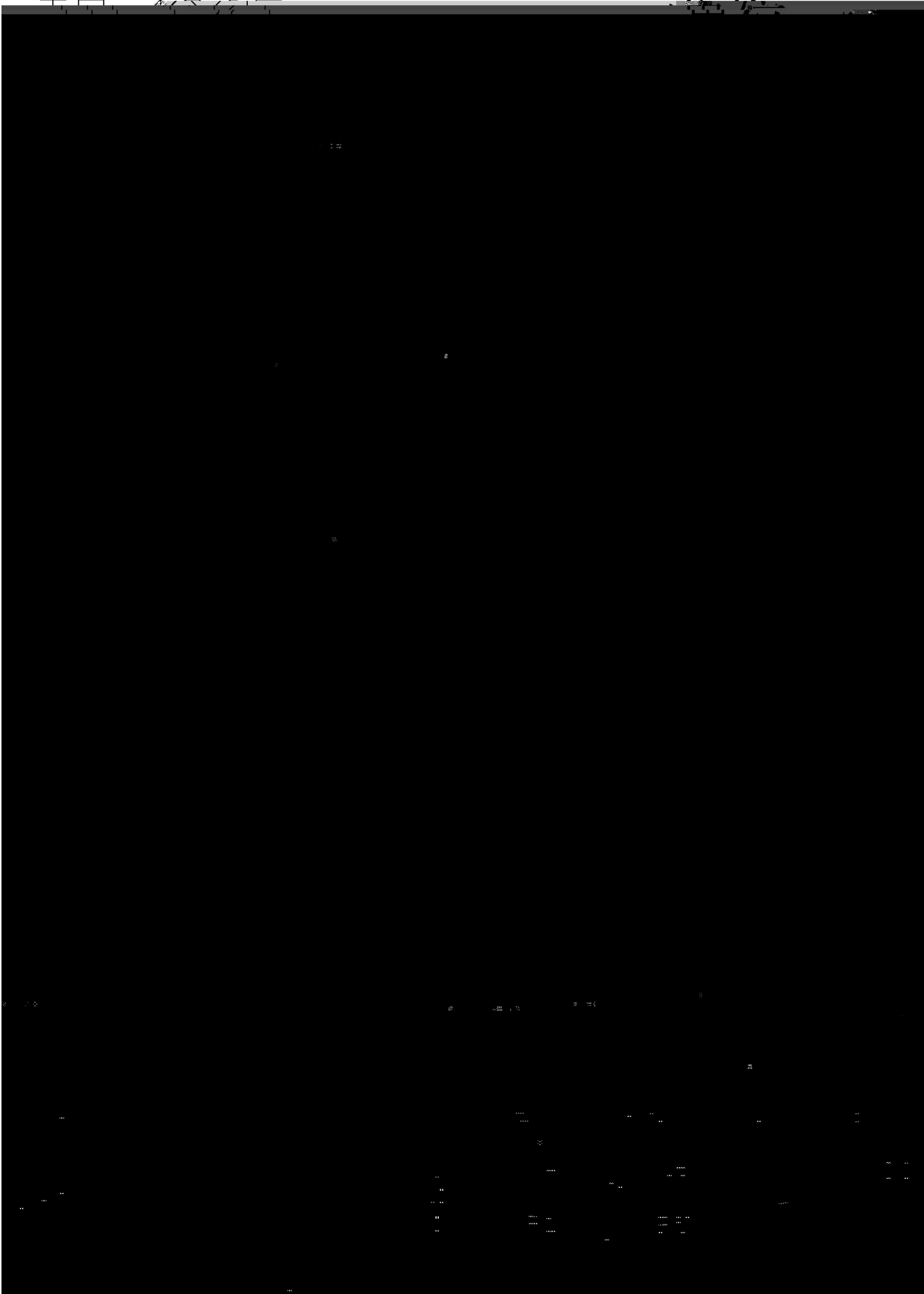
DATA SHEET

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	60	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	2.0	A
Collector Current – Continuous(Pulse)	I_{CP}	6.0	A
Collector Power Dissipation	P_C	1.0	W

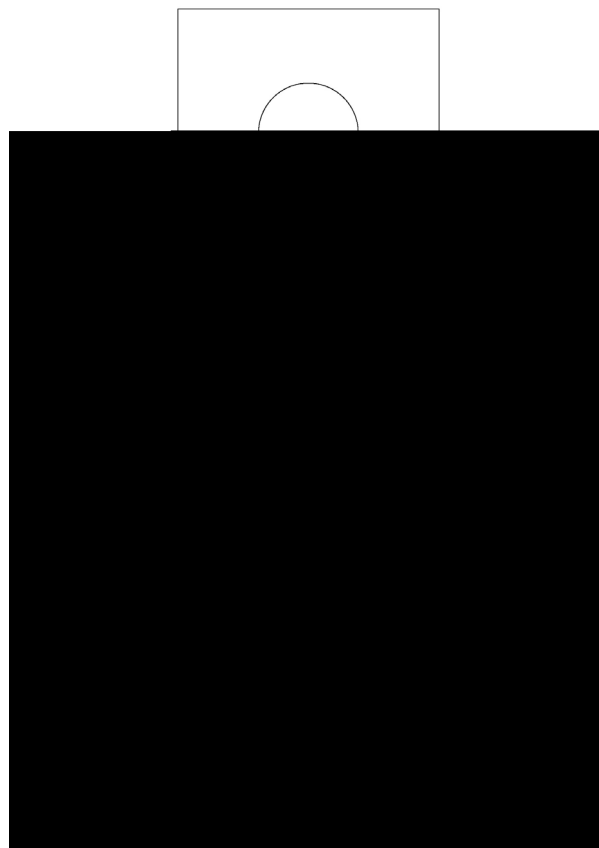
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions

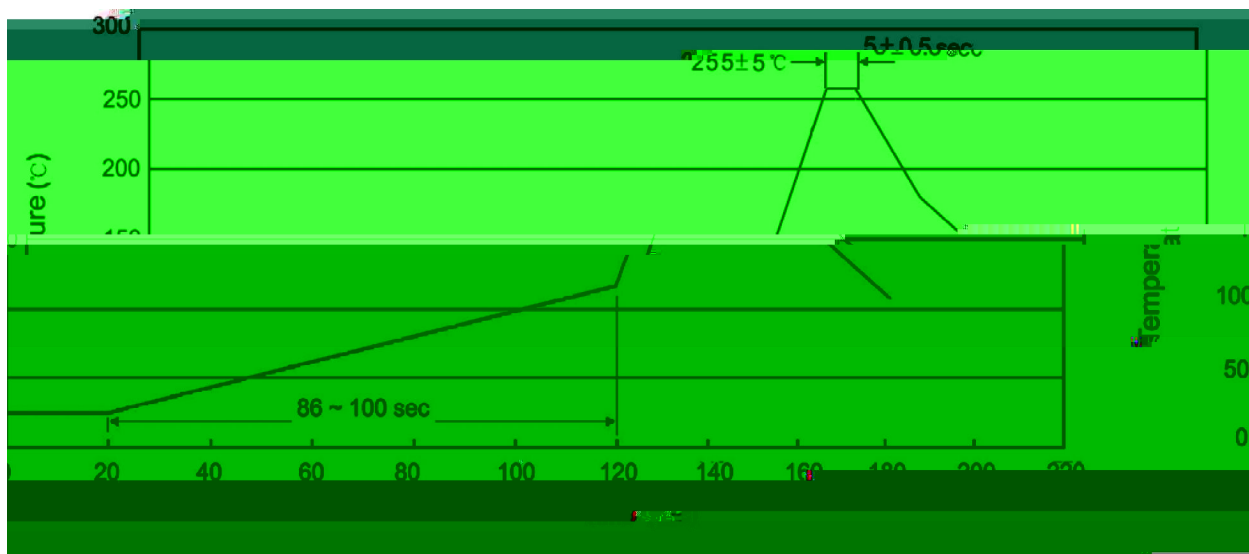


Note:

BR: Company Code

BD235: Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)


Note:

- | | | | | | |
|---|-----|-----|----|----------|--|
| 1 | 25 | 150 | 60 | 90sec; | 1. Preheating: 25~150 , Time: 60~90sec. |
| 2 | 255 | 5 | 5 | 0.5sec; | 2. Peak Temp.: 255 ± 5 , Duration: 5 ± 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270 ± 5 10 ± 1 sec. Temp.: 270±5 Time: 10±1 sec

/ Packaging SPEC.
/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-126/F	500	6	3,000	5	15,000	135×190	237×172×102	560×245×195

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-126/F	65	26	1,690	5	8,450	532×31×5.6	555×164×50	575×290×180

/ Notices